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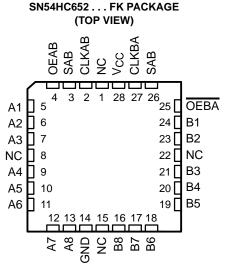
- Independent Registers and Enables for A and B Buses
- Multiplexed Real-Time and Stored Data
- True Data Paths
- High-Current 3-State Outputs Can Drive up to 15 LSTTL Loads
- Package Options Include Plastic Small-Outline (DW) and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (NT) and Ceramic (JT) 300-mil DIPs

description

These devices consist of bus-transceiver circuits, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the data bus or from the internal storage registers. Output-enable (OEAB and OEBA) inputs are provided to control the transceiver functions. Select-control (SAB and SBA) inputs are provided to select real-time or stored data transfer. A low input level selects real-time data, and a high input level selects stored data. Figure 1 illustrates the four fundamental bus-management functions that can be performed with the 'HC652.

Data on the A or B data bus, or both, can be stored in the internal D-type flip-flops by low-to-high transitions at the appropriate clock (CLKAB or CLKBA) terminals regardless of the select- or output-control terminals. When SAB and SBA are in the real-time transfer mode, it is possible to store data without using the internal D-type flip-flops by simultaneously enabling OEAB and OEBA. In this configuration, each output reinforces its input. When all other data sources to the two sets of bus lines are at high impedance, each set of bus lines remains at its last state.

CLKAB 1 24 V _{CC} SAB 2 23 CLKBA OEAB 3 22 SBA A1 4 21 OEBA A2 5 20 B1 A3 6 19 B2 A4 7 18 B3 A5 8 17 B4 A6 9 16 B5 A7 10 15 B6 A8 11 14 B7 GND 12 13 B8	SN54HC652 SN74HC652.		OR N	
	SAB [OEAB [A1 [A3 [A3 [A4 [A5 [A6 [A8 [3 4 5 6 7 8 9 10 11	23 22 21 20 19 18 17 16 15 14	CLKBA SBA OEBA B1 B2 B3 B4 B5 B6 B7



NC - No internal connection

The SN54HC652 is characterized for operation over the full military temperature range of -55° C to 125° C. The SN74HC652 is characterized for operation from -40° C to 85° C.



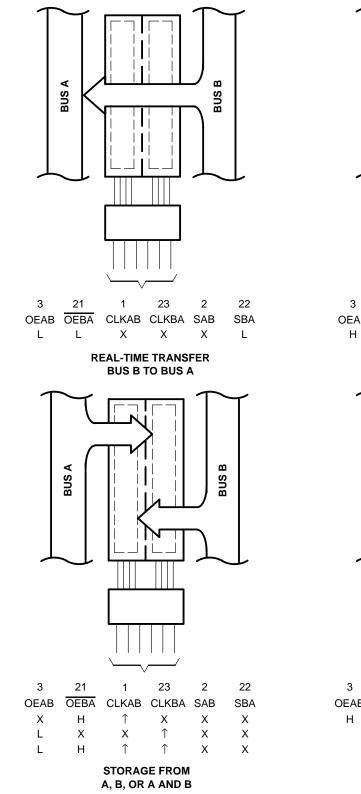
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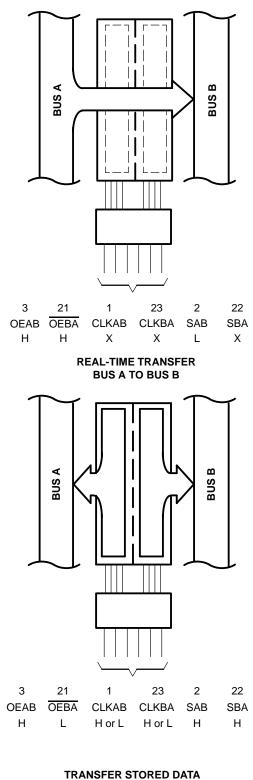
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TO A AND/OR B

Pin numbers shown are for the DW, JT, NT, and W packages.





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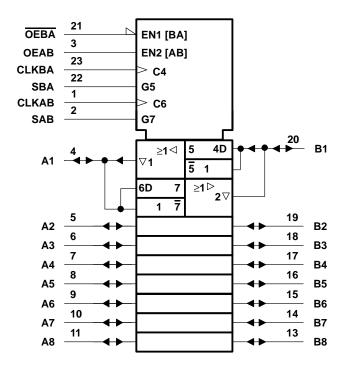
					FUI	NCTION TABLE		
		INPU [.]	TS			DATA	a 1/o†	OPERATION OR FUNCTION
OEAB	OEBA	CLKAB	CLKBA	SAB	SBA	A1–A8	B1–B8	OPERATION OR FUNCTION
L	Н	H or L	H or L	Х	Х	Input	Input	Isolation
L	н	\uparrow	\uparrow	Х	Х	Input	Input	Store A and B data
Х	Н	\uparrow	H or L	Х	Х	Input	Unspecified [‡]	Store A, hold B
н	н	\uparrow	\uparrow	X‡	Х	Input	Output	Store A in both registers
L	Х	H or L	\uparrow	Х	Х	Unspecified [‡]	Input	Hold A, store B
L	L	\uparrow	\uparrow	х	х‡	Output	Input	Store B in both registers
L	L	Х	Х	Х	L	Output	Input	Real-time B data to A bus
L	L	Х	H or L	х	н	Output	Input	Stored B data to A bus
н	Н	Х	Х	L	Х	Input	Output	Real-time A data to B bus
н	Н	H or L	Х	н	Х	Input	Output	Stored A data to B bus
н	L	H or L	H or L	Н	Н	Output	Output	Stored A data to B bus and stored B data to A bus

⁺ The data-output functions are enabled or disabled by a variety of level combinations at OEAB or OEBA. Data-input functions are always enabled; i.e., data at the bus terminals is stored on every low-to-high transition on the clock inputs.

[‡] Select control = L; clocks can occur simultaneously.

Select control = H; clocks must be staggered to load both registers.

logic symbol§

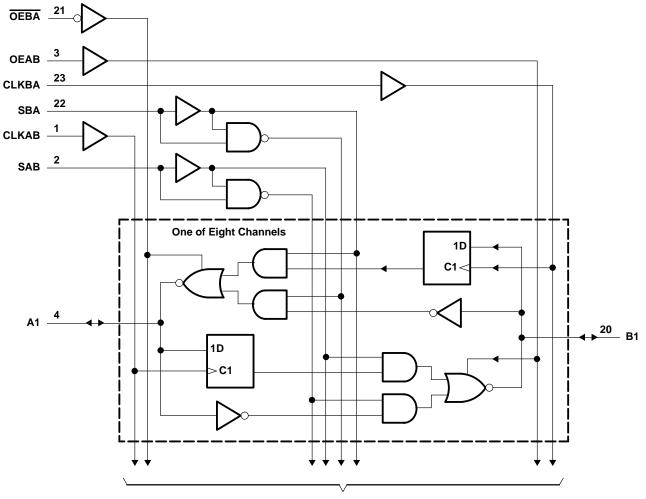


§ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the DW, JT, NT, and W packages.



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logic diagram (positive logic)



To Seven Other Channels

Pin numbers shown are for the DW, JT, NT, and W packages.

absolute maximum ratings over operating free-air temperature range[†]

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input clamp current, I _{IK} (V _I < 0 or V _I > V _{CC}) (see Note 1)	±20 mA
Output clamp current, I_{OK} (V _O < 0 or V _O > V _{CC}) (see Note 1)	±20 mA
Continuous output current, $I_O (V_O = 0 \text{ to } V_{CC})$	±35 mA
Continuous current through V _{CC} or GND	±70 mA
Package thermal impedance, θ_{JA} (see Note 2): DW package	81°C/W
NT package	67°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.



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recommended operating conditions

			SN	154HC65	52	SN74HC652			UNIT
			MIN NOM MAX			MIN	NOM	MAX	UNIT
Vcc	Supply voltage		2	5	6	2	5	6	V
		$V_{CC} = 2 V$	1.5			1.5			
ViH	High-level input voltage	V _{CC} = 4.5 V	3.15		1	3.15			V
		V _{CC} = 6 V	4.2		51	4.2			
		$V_{CC} = 2 V$	0	<i>IEL</i>	0.5	0		0.5	
VIL	Low-level input voltage	V _{CC} = 4.5 V	0	9	1.35	0		1.35	V
		V _{CC} = 6 V	0	S	1.8	0		1.8	
VI	Input voltage		0	2	VCC	0		VCC	V
VO	Output voltage		0		VCC	0		VCC	V
		$V_{CC} = 2 V$	0		1000	0		1000	
t _t	Input transition (rise and fall) time	V _{CC} = 4.5 V	0		500	0		500	ns
		V _{CC} = 6 V	0		400	0		400	
Тд	Operating free-air temperature		-55		125	-40		85	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	AMETER	TEST CO	NDITIONS	Vee	Т	A = 25°C	;	SN54H	IC652	SN74H	C652	UNIT
FAR/	AMETER	TEST CC	NDITIONS	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
				2 V	1.9	1.998		1.9		1.9		
			I _{OH} = -20 μA	4.5 V	4.4	4.499		4.4		4.4		
∨он		$V_I = V_{IH} \text{ or } V_{IL}$		6 V	5.9	5.999		5.9		5.9		V
			I _{OH} = -6 mA	4.5 V	3.98	4.3		3.7		3.84		
			I _{OH} = -7.8 mA	6 V	5.48	5.8		5.2	5W	5.34		
				2 V		0.002	0.1		0.1		0.1	
			I _{OL} = 20 μA	4.5 V		0.001	0.1	4	0.1		0.1	
VOL		$V_I = V_{IH} \text{ or } V_{IL}$		6 V		0.001	0.1	40	0.1		0.1	V
			IOL = 6 mA	4.5 V		0.17	0.26	n_Q	0.4		0.33	
			I _{OL} = 7.8 mA	6 V		0.15	0.26	DYC	0.4		0.33	
Ц	Control inputs	$V_{I} = V_{CC} \text{ or } 0$		6 V		±0.1	±100	Y	±1000		±1000	nA
Ioz	A or B	$V_{O} = V_{CC} \text{ or } GN$	D	6 V		±0.01	±0.5		±10		±5	μA
ICC		$V_I = V_{CC} \text{ or } 0,$	I ^O = 0	6 V			8		160		80	μA
Ci	Control inputs			2 V to 6 V		3	10		10		10	pF



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timing requirements over recommended operating free-air temperature range (unless otherwise noted)

		N.	T _A = 2	25°C	SN54H	IC652	SN74H	IC652	UNIT
		Vcc	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
		2 V	0	6	0	4.3	0	5.5	
fclock	Clock frequency	4.5 V	0	31	0	22	0	27	MHz
		6 V	0	36	0	25	0	31	
t _w	Pulse duration, CLKBA or CLKAB high or low	2 V	80		115	'VIE	95		
		4.5 V	16		23	RE	19		ns
			14		20	6	16		
		2 V	100		150		125		
t _{su}	Setup time, A before CLKAB \uparrow or B before CLKBA \uparrow	4.5 V	20		030		25		ns
		6 V	17		Q 26		21		
	Hold time, A after CLKAB↑ or B after CLKBA↑	2 V	5		5		5		ns
t _h		4.5 V	5		5		5		
			5		5		5		

switching characteristics over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	то	Vaa	T	4 = 25°C	;	SN54F	IC652	SN74H	IC652	UNIT
PARAMETER	(INPUT)	(OUTPUT)	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			2 V	6	10		4.3		5.5		
fmax			4.5 V	31	40		22		27		MHz
			6 V	36	45		25		31		
			2 V		65	180		270		225	
	CLKBA or CLKAB	A or B	4.5 V		18	36		54		45	
			6 V		14	31		46		38	
			2 V		50	135		205		170	
^t pd	A or B	B or A	4.5 V		14	27		41		34	ns
			6 V		11	23		35		29	
			2 V		70	190	4	285		240	
	SBA or SAB [†]	A or B	4.5 V		20	38	$\eta_{\eta_{c}}$	57		48	
			6 V		16	32	105	48		41	
			2 V		85	245	4	370		305	
t _{en}	OEBA or OEAB	A or B	4.5 V		25	49		74		61	ns
			6 V		20	42		63		52	
			2 V		50	245		370		305	
^t dis	OEBA or OEAB	A or B	4.5 V		23	49		74		61	ns
			6 V		20	42		63		52	
			2 V		28	60		90		75	
tt		Any	4.5 V		8	12		18		15	ns
			6 V		6	10		15		13	

[†] These parameters are measured with the internal output state of the storage register opposite that of the bus input.



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switching characteristics over recommended operating free-air temperature range, $C_L = 150 \text{ pF}$ (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	то	Vaa	T,	ן = 25°C	;	SN54H	C652	SN74H	IC652	UNIT
PARAMETER	(INPUT)	(OUTPUT)	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			2 V		90	265		400		330	
	CLKBA or CLKAB	A or B	4.5 V		24	53		80		66	
			6 V		18	46		68	MIN MAX 0 330 0 66 3 57 5 275 0 55 7 48 5 345 8 69 0 60 0 410 0 82 5 71		
			2 V		70	220		335		275	
^t pd	A or B	B or A	4.5 V		20	44		70		55	ns
			6 V		15	38		57		48	
			2 V		80	275	40	415		345	
	SBA or SAB†	A or B	4.5 V		24	55	ng	83		69	
			6 V		20	47	06	70		60	
			2 V		100	330	Q	500		410	
ten	OEBA or OEAB	A or B	4.5 V		33	66		100		82	ns
			6 V		27	57		85		71	
			2 V		45	210		315		265	
tt		Any	4.5 V		17	42		63		53	ns
			6 V		13	36		53		43	

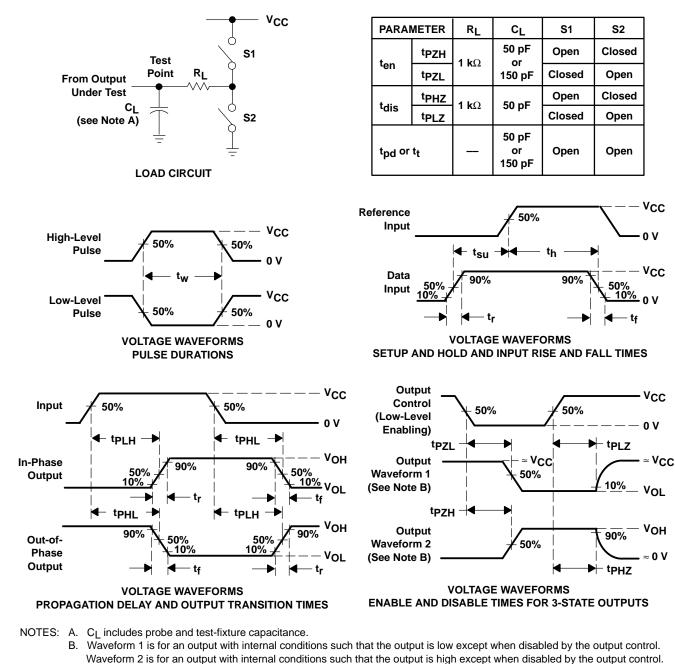
[†] These parameters are measured with the internal output state of the storage register opposite that of the bus input.

operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load	50	pF

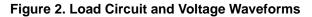


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PARAMETER MEASUREMENT INFORMATION

- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_Q = 50 Ω , t_f = 6 ns, t_f = 6 ns.
- D. For clock inputs, fmax is measured when the input duty cycle is 50%.
- E. The outputs are measured one at a time with one input transition per measurement.
- F. tpLz and tpHz are the same as tdis.
- G. t_{PZL} and t_{PZH} are the same as t_{en}.
- H. tPLH and tPHL are the same as tpd.





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